NSN 5962-01-356-8610

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View Online at https://aerobasegroup.com/nsn/5962-01-356-8610

Body Length: 0.540 inches **Body Width:** Between 0.250 inches and 0.370 inches **Body Height:** Between 0.045 inches and 0.092 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and monolithic and parallel operation **Inclosure Material:** Ceramic **Inclosure Configuration:** Flat pack **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 9 input **Case Outline Source And Designator:** F-10 mil-m-38510 **Current Rating Per Characteristic:** 90.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -0.5 volts power source and 7.0 volts power source **Capitance Rating Per Characteristic:** 7.00 input picofarads and 7.00 output picofarads **Time Rating Per Chacteristic:** 55.00 nanoseconds delay Memory Device Type: First-in first-out **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 18 flat leads Shelf Life:

N/a

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Unit Of Measure:

Demilitarization:

No

Fiig:

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